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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details

Product Status	Obsolete
Number of LABs/CLBs	2400
Number of Logic Elements/Cells	10800
Total RAM Bits	163840
Number of I/O	404
Number of Gates	569952
Voltage - Supply	1.71V ~ 1.89V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	560-LBGA Exposed Pad, Metal
Supplier Device Package	560-MBGA (42.5x42.5)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcv400e-7bg560i

The DLL also operates as a clock mirror. By driving the output from a DLL off-chip and then back on again, the DLL can be used to deskew a board level clock among multiple devices.

To guarantee that the system clock is operating correctly prior to the FPGA starting up after configuration, the DLL can delay the completion of the configuration process until after it has achieved lock. For more information about DLL functionality, see the Design Consideration section of the data sheet.

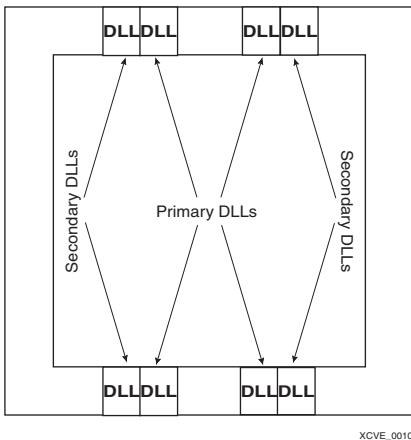


Figure 10: DLL Locations

Boundary Scan

Virtex-E devices support all the mandatory Boundary Scan instructions specified in the IEEE standard 1149.1. A Test Access Port (TAP) and registers are provided that implement the EXTEST, INTEST, SAMPLE/PRELOAD, BYPASS, IDCODE, USERCODE, and HIGHZ instructions. The TAP

also supports two internal scan chains and configuration/readback of the device.

The JTAG input pins (TDI, TMS, TCK) do not have a V_{CCO} requirement and operate with either 2.5 V or 3.3 V input signalling levels. The output pin (TDO) is sourced from the V_{CCO} in bank 2, and for proper operation of LVTTL 3.3 V levels, the bank should be supplied with 3.3 V.

Boundary Scan operation is independent of individual IOB configurations, and unaffected by package type. All IOBs, including un-bonded ones, are treated as independent 3-state bidirectional pins in a single scan chain. Retention of the bidirectional test capability after configuration facilitates the testing of external interconnections, provided the user design or application is turned off.

Table 6 lists the Boundary Scan instructions supported in Virtex-E FPGAs. Internal signals can be captured during EXTEST by connecting them to un-bonded or unused IOBs. They can also be connected to the unused outputs of IOBs defined as unidirectional input pins.

Before the device is configured, all instructions except USER1 and USER2 are available. After configuration, all instructions are available. During configuration, it is recommended that those operations using the Boundary Scan register (SAMPLE/PRELOAD, INTEST, EXTEST) not be performed.

In addition to the test instructions outlined above, the Boundary Scan circuitry can be used to configure the FPGA, and also to read back the configuration data.

Figure 11 is a diagram of the Virtex-E Series Boundary Scan logic. It includes three bits of Data Register per IOB, the IEEE 1149.1 Test Access Port controller, and the Instruction Register with decodes.

LVTTL 3-state output buffers have selectable drive strengths.

The format for LVTTL OBUFT symbol names is as follows:

OBUFT_<slew_rate>_<drive_strength>

where <slew_rate> is either F (Fast) or S (Slow), and <drive_strength> is specified in millamps (2, 4, 6, 8, 12, 16, or 24).

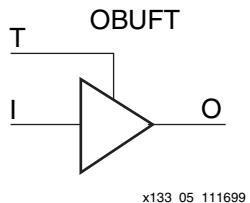


Figure 41: 3-State Output Buffer Symbol (OBUFT)

The following list details variations of the OBUFT symbol.

- OBUFT
- OBUFT_S_2
- OBUFT_S_4
- OBUFT_S_6
- OBUFT_S_8
- OBUFT_S_12
- OBUFT_S_16
- OBUFT_S_24
- OBUFT_F_2
- OBUFT_F_4
- OBUFT_F_6
- OBUFT_F_8
- OBUFT_F_12
- OBUFT_F_16
- OBUFT_F_24
- OBUFT_LVCMOS2
- OBUFT_PCI33_3
- OBUFT_PCI66_3
- OBUFT_GTL
- OBUFT_GTL_P
- OBUFT_HSTL_I
- OBUFT_HSTL_III
- OBUFT_HSTL_IV
- OBUFT_SSTL3_I
- OBUFT_SSTL3_II
- OBUFT_SSTL2_I
- OBUFT_SSTL2_II
- OBUFT_CTT
- OBUFT_AG
- OBUFT_LVCMOS18
- OBUFT_LVDS
- OBUFT_LVPECL

The Virtex-E series supports eight banks for the HQ and PQ packages. The CS package supports four V_{CCO} banks.

The SelectI/O OBUFT placement restrictions require that within a given V_{CCO} bank each OBUFT share the same output source drive voltage. Input buffers of any type and output buffers that do not require V_{CCO} can be placed within the same V_{CCO} bank.

The LOC property can specify a location for the OBUFT.

3-state output buffers and bidirectional buffers can have either a weak pull-up resistor, a weak pull-down resistor, or a weak “keeper” circuit. Control this feature by adding the appropriate symbol to the output net of the OBUFT (PULLUP, PULLDOWN, or KEEPER).

The weak “keeper” circuit requires the input buffer within the IOB to sample the I/O signal. So, OBUFTs programmed for an I/O standard that requires a V_{REF} have automatic placement of a V_{REF} in the bank with an OBUFT configured with a weak “keeper” circuit. This restriction does not affect most circuit design as applications using an OBUFT configured with a weak “keeper” typically implement a bidirectional I/O. In this case the IBUF (and the corresponding V_{REF}) are explicitly placed.

The LOC property can specify a location for the OBUFT.

IOBUF

Use the IOBUF symbol for bidirectional signals that require both an input buffer and a 3-state output buffer with an active high 3-state pin. The generic input/output buffer IOBUF appears in Figure 42.

The extension to the base name defines which I/O standard the IOBUF uses. With no extension specified for the generic IOBUF symbol, the assumed standard is LVTTL input buffer and slew rate limited LVTTL with 12 mA drive strength for the output buffer.

The LVTTL IOBUF additionally can support one of two slew rate modes to minimize bus transients. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals.

LVTTL bidirectional buffers have selectable output drive strengths.

The format for LVTTL IOBUF symbol names is as follows:

IOBUF_<slew_rate>_<drive_strength>

where <slew_rate> is either F (Fast) or S (Slow), and <drive_strength> is specified in millamps (2, 4, 6, 8, 12, 16, or 24).

Table 42: Input Library Macros

Name	Inputs	Outputs
IBUFDS_FD_LVDS	I, IB, C	Q
IBUFDS_FDE_LVDS	I, IB, CE, C	Q
IBUFDS_FDC_LVDS	I, IB, C, CLR	Q
IBUFDS_FDCE_LVDS	I, IB, CE, C, CLR	Q
IBUFDS_FDP_LVDS	I, IB, C, PRE	Q
IBUFDS_FDPE_LVDS	I, IB, CE, C, PRE	Q
IBUFDS_FDR_LVDS	I, IB, C, R	Q
IBUFDS_FDRE_LVDS	I, IB, CE, C, R	Q
IBUFDS_FDS_LVDS	I, IB, C, S	Q
IBUFDS_FDSE_LVDS	I, IB, CE, C, S	Q
IBUFDS_LD_LVDS	I, IB, G	Q
IBUFDS_LDE_LVDS	I, IB, GE, G	Q
IBUFDS_LDC_LVDS	I, IB, G, CLR	Q
IBUFDS_LDCE_LVDS	I, IB, GE, G, CLR	Q
IBUFDS_LDP_LVDS	I, IB, G, PRE	Q
IBUFDS_LDPE_LVDS	I, IB, GE, G, PRE	Q

Creating LVDS Output Buffers

LVDS output buffers can be placed in a wide number of IOB locations. The exact locations are dependent on the package used. The Virtex-E package information lists the possible locations as IO_L#P for the P-side and IO_L#N for the N-side, where # is the pair number.

HDL Instantiation

Both output buffers are required to be instantiated in the design and placed on the correct IO_L#P and IO_L#N locations. The IOB must have the same net source the following pins, clock (C), set/reset (SR), output (O), output clock enable (OCE). In addition, the output (O) pins must be inverted with respect to each other, and if output registers are used, the INIT states must be opposite values (one HIGH and one LOW). Failure to follow these rules leads to DRC errors in software.

VHDL Instantiation

```

data0_p : OBDFL_LVDS port map
(I=>data_int(0), O=>data_p(0));

data0_inv: INV      port map
(I=>data_int(0), O=>data_n_int(0));

data0_n : OBDFL_LVDS port map
(I=>data_n_int(0), O=>data_n(0));

```

Verilog Instantiation

```

OBDFL_LVDS data0_p (.I(data_int[0]),
.O(data_p[0]));

INV      data0_inv (.I(data_int[0]),
.O(data_n_int[0]));

OBDFL_LVDS data0_n (.I(data_n_int[0]),
.O(data_n[0]));

```

Location Constraints

All LVDS buffers must be explicitly placed on a device. For the output buffers this can be done with the following constraint in the .ucf or .ncf file.

```

NET data_p<0> LOC = D28; # IO_L0P
NET data_n<0> LOC = B29; # IO_L0N

```

Synchronous vs. Asynchronous Outputs

If the outputs are synchronous (registered in the IOB) then any IO_L#PIN pair can be used. If the outputs are asynchronous (no output register), then they must use one of the pairs that are part of the same IOB group at the end of a ROW or COLUMN in the device.

The LVDS pairs that can be used as asynchronous outputs are listed in the Virtex-E pinout tables. Some pairs are marked as asynchronous-capable for all devices in that package, and others are marked as available only for that device in the package. If the device size might change at some point in the product lifetime, then only the common pairs for all packages should be used.

Adding an Output Register

All LVDS buffers can have an output register in the IOB. The output registers must be in both the P-side and N-side IOBs. All the normal IOB register options are available (FD, FDE, FDC, FDCE, FDP, FDPE, FDR, FDRE, FDS, FDSE, LD, LDE, LDC, LDCE, LDP, LDPE). The register elements can be inferred or explicitly instantiated in the HDL code.

Special care must be taken to insure that the D pins of the registers are inverted and that the INIT states of the registers are opposite. The clock pin (C), clock enable (CE) and set/reset (CLR/PRE or S/R) pins must connect to the same source. Failure to do this leads to a DRC error in the software.

The register elements can be packed in the IOB using the IOB property to TRUE on the register or by using the “map -pr [ilob]” where “i” is inputs only, “o” is outputs only and “b” is both inputs and outputs.

To improve design coding times VHDL and Verilog synthesis macro libraries have been developed to explicitly create these structures. The output library macros are listed in [Table 43](#). The O and OB inputs to the macros are the external net connections.

Date	Version	Revision
9/20/00	1.7	<ul style="list-style-type: none"> Min values added to Virtex-E Electrical Characteristics tables. XCV2600E and XCV3200E numbers added to Virtex-E Electrical Characteristics tables (Module 3). Corrected user I/O count for XCV100E device in Table 1 (Module 1). Changed several pins to “No Connect in the XCV100E” and removed duplicate V_{CCINT} pins in Table ~ (Module 4). Changed pin J10 to “No connect in XCV600E” in Table 74 (Module 4). Changed pin J30 to “VREF option only in the XCV600E” in Table 74 (Module 4). Corrected pair 18 in Table 75 (Module 4) to be “AO in the XCV1000E, XCV1600E”.
11/20/00	1.8	<ul style="list-style-type: none"> Upgraded speed grade -8 numbers in Virtex-E Electrical Characteristics tables to Preliminary. Updated minimums in Table 13 and added notes to Table 14. Added to note 2 to Absolute Maximum Ratings. Changed speed grade -8 numbers for $T_{SHCKO32}$, T_{REG}, T_{BCCS}, and T_{ICKOF}. Changed all minimum hold times to -0.4 under Global Clock Set-Up and Hold for LVTTL Standard, with DLL. Revised maximum T_{DLLPW} in -6 speed grade for DLL Timing Parameters. Changed GCLK0 to BA22 for FG860 package in Table 46.
2/12/01	1.9	<ul style="list-style-type: none"> Revised footnote for Table 14. Added numbers to Virtex-E Electrical Characteristics tables for XCV1000E and XCV2000E devices. Updated Table 27 and Table 78 to include values for XCV400E and XCV600E devices. Revised Table 62 to include pinout information for the XCV400E and XCV600E devices in the BG560 package. Updated footnotes 1 and 2 for Table 76 to include XCV2600E and XCV3200E devices.
4/02/01	2.0	<ul style="list-style-type: none"> Updated numerous values in Virtex-E Switching Characteristics tables. Converted data sheet to modularized format. See the Virtex-E Data Sheet section.
4/19/01	2.1	<ul style="list-style-type: none"> Modified Figure 30 "DLL Generation of 4x Clock in Virtex-E Devices."
07/23/01	2.2	<ul style="list-style-type: none"> Made minor edits to text under Configuration. Added CLB column locations for XCV2600E and XCV3200E devices in Table 3.
11/09/01	2.3	<ul style="list-style-type: none"> Added warning under Configuration section that attempting to load an incorrect bitstream causes configuration to fail and can damage the device.
07/17/02	2.4	<ul style="list-style-type: none"> Data sheet designation upgraded from Preliminary to Production.
09/10/02	2.5	<ul style="list-style-type: none"> Added clarification to the Input/Output Block, Configuration, Boundary Scan Mode, and Block SelectRAM sections. Revised Figure 18, Table 11, and Table 36.
11/19/02	2.6	<ul style="list-style-type: none"> Added clarification in the Boundary Scan section. Removed last sentence regarding deactivation of duty-cycle correction in Duty Cycle Correction Property section.
06/15/04	2.6.1	<ul style="list-style-type: none"> Updated clickable web addresses.
01/12/06	2.7	<ul style="list-style-type: none"> Updated the Slave-Serial Mode and the Master-Serial Mode sections.
01/16/06	2.8	<ul style="list-style-type: none"> Made minor updates to Table 8.

DC Characteristics Over Recommended Operating Conditions

Symbol	Description		Device	Min	Max	Units
V_{DRINT}	Data Retention V_{CCINT} Voltage (below which configuration data might be lost)		All	1.5		V
V_{DRIQ}	Data Retention V_{CCO} Voltage (below which configuration data might be lost)		All	1.2		V
I_{CCINTQ}	Quiescent V_{CCINT} supply current (Note 1)		XCV50E	200	mA	
			XCV100E	200	mA	
			XCV200E	300	mA	
			XCV300E	300	mA	
			XCV400E	300	mA	
			XCV600E	400	mA	
			XCV1000E	500	mA	
			XCV1600E	500	mA	
			XCV2000E	500	mA	
			XCV2600E	500	mA	
			XCV3200E	500	mA	
I_{CCOQ}	Quiescent V_{CCO} supply current (Note 1)		XCV50E	2	mA	
			XCV100E	2	mA	
			XCV200E	2	mA	
			XCV300E	2	mA	
			XCV400E	2	mA	
			XCV600E	2	mA	
			XCV1000E	2	mA	
			XCV1600E	2	mA	
			XCV2000E	2	mA	
			XCV2600E	2	mA	
			XCV3200E	2	mA	
I_L	Input or output leakage current		All	-10	+10	μA
C_{IN}	Input capacitance (sample tested)	BGA, PQ, HQ, packages	All		8	pF
I_{RPU}	Pad pull-up (when selected) @ $V_{in} = 0$ V, $V_{CCO} = 3.3$ V (sample tested)		All	Note 2	0.25	mA
I_{RPD}	Pad pull-down (when selected) @ $V_{in} = 3.6$ V (sample tested)			Note 2	0.25	mA

Notes:

- With no output current loads, no active input pull-up resistors, all I/O pins 3-stated and floating.
- Internal pull-up and pull-down resistors guarantee valid logic levels at unconnected input pins. These pull-up and pull-down resistors do not guarantee valid logic levels when input pins are connected to other circuits.

Input/Output Standard	V _{IL}		V _{IH}		V _{OL}	V _{OH}	I _{OL}	I _{OH}
	V, Min	V, Max	V, Min	V, Max	V, Max	V, Min	mA	mA
CTT	-0.5	V _{REF} - 0.2	V _{REF} + 0.2	3.6	V _{REF} - 0.4	V _{REF} + 0.4	8	-8
AGP	-0.5	V _{REF} - 0.2	V _{REF} + 0.2	3.6	10% V _{CCO}	90% V _{CCO}	Note 2	Note 2

Notes:

1. V_{OL} and V_{OH} for lower drive currents are sample tested.
2. Tested according to the relevant specifications.
3. DC input and output levels for HSTL18 (HSTL I/O standard with V_{CCO} of 1.8 V) are provided in an HSTL white paper on www.xilinx.com.

LVDS DC Specifications

DC Parameter	Symbol	Conditions	Min	Typ	Max	Units
Supply Voltage	V _{CCO}		2.375	2.5	2.625	V
Output High Voltage for Q and \bar{Q}	V _{OH}	R _T = 100 Ω across Q and \bar{Q} signals	1.25	1.425	1.6	V
Output Low Voltage for Q and \bar{Q}	V _{OL}	R _T = 100 Ω across Q and \bar{Q} signals	0.9	1.075	1.25	V
Differential Output Voltage (Q - \bar{Q}), Q = High (\bar{Q} - Q), \bar{Q} = High	V _{ODIFF}	R _T = 100 Ω across Q and \bar{Q} signals	250	350	450	mV
Output Common-Mode Voltage	V _{OCM}	R _T = 100 Ω across Q and \bar{Q} signals	1.125	1.25	1.375	V
Differential Input Voltage (Q - \bar{Q}), Q = High (\bar{Q} - Q), \bar{Q} = High	V _{IDIFF}	Common-mode input voltage = 1.25 V	100	350	NA	mV
Input Common-Mode Voltage	V _{ICM}	Differential input voltage = ±350 mV	0.2	1.25	2.2	V

Note: Refer to the Design Consideration section for termination schematics.

LVPECL DC Specifications

These values are valid at the output of the source termination pack shown under **LVPECL**, with a 100 Ω differential load only. The V_{OH} levels are 200 mV below standard LVPECL levels and are compatible with devices tolerant of lower common-mode ranges. The following table summarizes the DC output specifications of LVPECL.

DC Parameter	Min	Max	Min	Max	Min	Max	Units
V _{CCO}	3.0		3.3		3.6		V
V _{OH}	1.8	2.11	1.92	2.28	2.13	2.41	V
V _{OL}	0.96	1.27	1.06	1.43	1.30	1.57	V
V _{IH}	1.49	2.72	1.49	2.72	1.49	2.72	V
V _{IL}	0.86	2.125	0.86	2.125	0.86	2.125	V
Differential Input Voltage	0.3	-	0.3	-	0.3	-	V

IOB Output Switching Characteristics Standard Adjustments

Output delays terminating at a pad are specified for LVTTL with 12 mA drive and fast slew rate. For other standards, adjust the delays by the values shown.

Description	Symbol	Standard	Speed Grade				Units
			Min	-8	-7	-6	
Output Delay Adjustments							
Standard-specific adjustments for output delays terminating at pads (based on standard capacitive load, C _{SL})	T _{OLVTTL_S2}	LVTTL, Slow, 2 mA	4.2	+14.7	+14.7	+14.7	ns
	T _{OLVTTL_S4}	4 mA	2.5	+7.5	+7.5	+7.5	ns
	T _{OLVTTL_S6}	6 mA	1.8	+4.8	+4.8	+4.8	ns
	T _{OLVTTL_S8}	8 mA	1.2	+3.0	+3.0	+3.0	ns
	T _{OLVTTL_S12}	12 mA	1.0	+1.9	+1.9	+1.9	ns
	T _{OLVTTL_S16}	16 mA	0.9	+1.7	+1.7	+1.7	ns
	T _{OLVTTL_S24}	24 mA	0.8	+1.3	+1.3	+1.3	ns
	T _{OLVTTL_F2}	LVTTL, Fast, 2 mA	1.9	+13.1	+13.1	+13.1	ns
	T _{OLVTTL_F4}	4 mA	0.7	+5.3	+5.3	+5.3	ns
	T _{OLVTTL_F6}	6 mA	0.20	+3.1	+3.1	+3.1	ns
	T _{OLVTTL_F8}	8 mA	0.10	+1.0	+1.0	+1.0	ns
	T _{OLVTTL_F12}	12 mA	0.0	0.0	0.0	0.0	ns
	T _{OLVTTL_F16}	16 mA	-0.10	-0.05	-0.05	-0.05	ns
	T _{OLVTTL_F24}	24 mA	-0.10	-0.20	-0.20	-0.20	ns
	T _{OLVCMOS_2}	LVCMOS2	0.10	+0.09	+0.09	+0.09	ns
	T _{OLVCMOS_18}	LVCMOS18	0.10	+0.7	+0.7	+0.7	ns
	T _{OLVDS}	LVDS	-0.39	-1.2	-1.2	-1.2	ns
	T _{OLVPECL}	LVPECL	-0.20	-0.41	-0.41	-0.41	ns
	T _{OPCI33_3}	PCI, 33 MHz, 3.3 V	0.50	+2.3	+2.3	+2.3	ns
	T _{OPCI66_3}	PCI, 66 MHz, 3.3 V	0.10	-0.41	-0.41	-0.41	ns
	T _{O GTL}	GTL	0.6	+0.49	+0.49	+0.49	ns
	T _{O GTLP}	GTL+	0.7	+0.8	+0.8	+0.8	ns
	T _{O HSTL_I}	HSTL I	0.10	-0.51	-0.51	-0.51	ns
	T _{O HSTL_III}	HSTL III	-0.10	-0.91	-0.91	-0.91	ns
	T _{O HSTL_IV}	HSTL IV	-0.20	-1.01	-1.01	-1.01	ns
	T _{O SSTL2_I}	SSTL2 I	-0.10	-0.51	-0.51	-0.51	ns
	T _{O SSTL2_II}	SSTL2 II	-0.20	-0.91	-0.91	-0.91	ns
	T _{O SSTL3_I}	SSTL3 I	-0.20	-0.51	-0.51	-0.51	ns
	T _{O SSTL3_II}	SSTL3 II	-0.30	-1.01	-1.01	-1.01	ns
	T _{O CTT}	CTT	0.0	-0.61	-0.61	-0.61	ns
	T _{O AGP}	AGP	-0.1	-0.91	-0.91	-0.91	ns

Table 6: PQ240 — XCV50E, XCV100E, XCV200E, XCV300E, XCV400E

Pin #	Pin Description	Bank
P173	IO_L16N_Y	2
P171	IO_VREF_L17P_Y	2
P170	IO_L17N_Y	2
P169	IO	2
P168 ¹	IO_VREF_L18P_Y	2
P167	IO_D1_L18N_Y	2
P163	IO_D2_L19P_YY	2
P162	IO_L19N_YY	2
P161	IO	2
P160	IO_L20P_Y	2
P159	IO_L20N_Y	2
P157	IO_VREF_L21P_Y	2
P156	IO_D3_L21N_Y	2
P155	IO_L22P_Y	2
P154 ³	IO_VREF_L22N_Y	2
P153	IO_L23P_YY	2
P152	IO_L23N_YY	2
P149	IO	3
P147 ³	IO_VREF	3
P145	IO_D4_L24P_Y	3
P144	IO_VREF_L24N_Y	3
P142	IO_L25P_Y	3
P141	IO_L25N_Y	3
P140	IO	3
P139	IO_L26P_YY	3
P138	IO_D5_L26N_YY	3
P134	IO_D6_L27P_Y	3
P133 ¹	IO_VREF_L27N_Y	3
P132	IO	3
P131	IO_L28P_Y	3
P130	IO_VREF_L28N_Y	3
P128	IO_L29P_Y	3
P127	IO_L29N_Y	3
P126 ²	IO_VREF_L30P_Y	3

Table 6: PQ240 — XCV50E, XCV100E, XCV200E, XCV300E, XCV400E

Pin #	Pin Description	Bank
P125	IO_L30N_Y	3
P124	IO_D7_L31P_YY	3
P123	IO_INIT_L31N_YY	3
P118	IO_L32P_YY	4
P117	IO_L32N_YY	4
P115 ²	IO_VREF	4
P114	IO_L33P_YY	4
P113	IO_L33N_YY	4
P111	IO_VREF_L34P_YY	4
P110	IO_L34N_YY	4
P109	IO	4
P108 ¹	IO_VREF_L35P_YY	4
P107	IO_L35N_YY	4
P103	IO_L36P_YY	4
P102	IO_L36N_YY	4
P101	IO	4
P100	IO_L37P_Y	4
P99	IO_L37N_Y	4
P97	IO_VREF_L38P_Y	4
P96	IO_L38N_Y	4
P95	IO_L39P_Y	4
P94 ³	IO_VREF_L39N_Y	4
P93	IO_LVDS_DLL_L40P	4
P92	GCK0	4
P89	GCK1	5
P87	IO_LVDS_DLL_L40N	5
P86 ³	IO_VREF	5
P84	IO_VREF_L41P_Y	5
P82	IO_L41N_Y	5
P81	IO	5
P80	IO	5
P79	IO_L42P_YY	5
P78	IO_L42N_YY	5

Table 10: BG352 — XCV100E, XCV200E, XCV300E

Bank	Pin Description	Pin #
0	IO	C15
0	IO	B15 ¹
0	IO_LVDS_DLL_L9N	A15
0	GCK3	D14
1	GCK2	B14
1	IO_LVDS_DLL_L9P	A13
1	IO	B13 ¹
1	IO_L10N	C13
1	IO_L10P	A12
1	IO_L11N_Y	B12
1	IO_VREF_1_L11P_Y	C12
1	IO_L12N_Y	A11
1	IO_L12P_Y	B11
1	IO	B10 ¹
1	IO_L13N	C11
1	IO_L13P	D11
1	IO	A9 ¹
1	IO_L14N YY	B9
1	IO_L14P YY	C10
1	IO_L15N YY	B8
1	IO_VREF_1_L15P YY	C9
1	IO_L16N_Y	D9
1	IO_L16P_Y	A7
1	IO	B7
1	IO	C8 ¹
1	IO	D8 ¹
1	IO_L17N YY	A6
1	IO_VREF_1_L17P YY	B6
1	IO_L18N YY	C7
1	IO_L18P YY	A4
1	IO	B5 ¹
1	IO_L19N YY	C6
1	IO_VREF_1_L19P YY	D6 ²

Table 10: BG352 — XCV100E, XCV200E, XCV300E

Bank	Pin Description	Pin #
1	IO	B4
1	IO	C5 ¹
1	IO	A3 ¹
1	IO_WRITE_L20N YY	D5
1	IO_CS_L20P YY	C4
2	IO_DOUT_BUSY_L21P YY	E4
2	IO_DIN_D0_L21N YY	D3
2	IO	C2 ¹
2	IO	E3 ¹
2	IO	F4
2	IO_VREF_2_L22P YY	D2 ²
2	IO_L22N YY	C1
2	IO	D1 ¹
2	IO_L23P YY	G4
2	IO_L23N YY	F3
2	IO_VREF_2_L24P_Y	E2
2	IO_L24N_Y	F2
2	IO	G3 ¹
2	IO	G2 ¹
2	IO_L25P	F1
2	IO_L25N	J4
2	IO	H3
2	IO_VREF_2_L26P_Y	H2
2	IO_D1_L26N_Y	G1
2	IO_D2_L27P YY	J3
2	IO_L27N YY	J2
2	IO	K3 ¹
2	IO_L28P	J1
2	IO_L28N	L4
2	IO	K2 ¹
2	IO_L29P YY	L3
2	IO_L29N YY	L2
2	IO_VREF_2_L30P_Y	M4

Table 12: BG432 — XCV300E, XCV400E, XCV600E

Bank	Pin Description	Pin #
2	IO_L41N_Y	H2
2	IO_VREF_L42P_Y	H1 ¹
2	IO_L42N_Y	J4
2	IO_VREF_L43P_YY	J2
2	IO_D1_L43N_YY	K4
2	IO_D2_L44P_YY	K2
2	IO_L44N_YY	K1
2	IO_L45P_Y	L2
2	IO_L45N_Y	M4
2	IO_L46P_Y	M3
2	IO_L46N_Y	M2
2	IO_L47P_Y	N4
2	IO_L47N_Y	N3
2	IO_VREF_L48P_YY	N1
2	IO_D3_L48N_YY	P4
2	IO_L49P_Y	P3
2	IO_L49N_Y	P2
2	IO_VREF_L50P_Y	R3 ²
2	IO_L50N_Y	R4
2	IO_L51P_YY	R1
2	IO_L51N_YY	T3
3	IO	AA2
3	IO	AC2
3	IO	AE2
3	IO	U3
3	IO	W1
3	IO_L52P_Y	U4
3	IO_VREF_L52N_Y	U2 ²
3	IO_L53P_Y	U1
3	IO_L53N_Y	V3
3	IO_D4_L54P_YY	V4
3	IO_VREF_L54N_YY	V2
3	IO_L55P_Y	W3
3	IO_L55N_Y	W4
3	IO_L56P_Y	Y1

Table 12: BG432 — XCV300E, XCV400E, XCV600E

Bank	Pin Description	Pin #
3	IO_L56N_Y	Y3
3	IO_L57P_Y	Y4
3	IO_L57N_Y	Y2
3	IO_L58P_YY	AA3
3	IO_D5_L58N_YY	AB1
3	IO_D6_L59P_YY	AB3
3	IO_VREF_L59N_YY	AB4
3	IO_L60P_Y	AD1
3	IO_VREF_L60N_Y	AC3 ¹
3	IO_L61P_Y	AC4
3	IO_L61N_Y	AD2
3	IO_L62P_YY	AD3
3	IO_VREF_L62N_YY	AD4
3	IO_L63P_Y	AF2
3	IO_L63N_Y	AE3
3	IO_L64P	AE4
3	IO_L64N	AG1
3	IO_L65P_Y	AG2
3	IO_VREF_L65N_Y	AF3
3	IO_L66P_Y	AF4
3	IO_L66N_Y	AH1
3	IO_L67P	AH2
3	IO_L67N	AG3
3	IO_D7_L68P_YY	AG4
3	IO_INIT_L68N_YY	AJ2
3	IO	T2
4	GCK0	AL16
4	IO	AH10
4	IO	AJ11
4	IO	AK7
4	IO	AL12
4	IO	AL15
4	IO_L69P_YY	AJ4
4	IO_L69N_YY	AK3
4	IO_L70P_Y	AH5

Table 14: BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin#	See Note
4	IO_L104N_YY	AJ12	
4	IO_L105P_Y	AN11	
4	IO_L105N_Y	AK12	
4	IO_L106P_YY	AL12	
4	IO_L106N_YY	AM12	
4	IO_VREF_L107P_YY	AK13	3
4	IO_L107N_YY	AL13	
4	IO_L108P_Y	AM13	
4	IO_L108N_Y	AN13	
4	IO_L109P_YY	AJ14	
4	IO_L109N_YY	AK14	
4	IO_VREF_L110P_YY	AM14	
4	IO_L110N_YY	AN15	
4	IO_L111P_Y	AJ15	
4	IO_L111N_Y	AK15	
4	IO_L112P_Y	AL15	
4	IO_L112N_Y	AM16	
4	IO_VREF_L113P_Y	AL16	
4	IO_L113N_Y	AJ16	
4	IO_L114P_Y	AK16	
4	IO_VREF_L114N_Y	AN17	2
4	IO_LVDS_DLL_L115P	AM17	
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5	GCK1	AJ17	
5	IO	AL25	
5	IO	AL28	
5	IO	AL30	
5	IO	AN28	
5	IO_LVDS_DLL_L115N	AM18	
5	IO_VREF	AL18	2
5	IO_L116P_Y	AK18	
5	IO_VREF_L116N_Y	AJ18	
5	IO_L117P_Y	AN19	
5	IO_L117N_Y	AL19	
5	IO_L118P_Y	AK19	

Table 14: BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin#	See Note
5	IO_L118N_Y	AM20	
5	IO_L119P_YY	AJ19	
5	IO_VREF_L119N_YY	AL20	
5	IO_L120P_YY	AN21	
5	IO_L120N_YY	AL21	
5	IO_L121P_Y	AJ20	
5	IO_L121N_Y	AM22	
5	IO_L122P_YY	AK21	
5	IO_VREF_L122N_YY	AN23	3
5	IO_L123P_YY	AJ21	
5	IO_L123N_YY	AM23	
5	IO_L124P_Y	AK22	
5	IO_L124N_Y	AM24	
5	IO_L125P_YY	AL23	
5	IO_L125N_YY	AJ22	
5	IO_L126P_YY	AK23	
5	IO_VREF_L126N_YY	AL24	
5	IO_L127P_Y	AN26	
5	IO_L127N_Y	AJ23	
5	IO_L128P_Y	AK24	
5	IO_VREF_L128N_Y	AM26	4
5	IO_L129P_Y	AM27	
5	IO_L129N_Y	AJ24	
5	IO_L130P_Y	AL26	
5	IO_VREF_L130N_Y	AK25	1
5	IO_L131P_YY	AN29	
5	IO_VREF_L131N_YY	AJ25	
5	IO_L132P_YY	AK26	
5	IO_L132N_YY	AM29	
5	IO_L133P_Y	AM30	
5	IO_L133N_Y	AJ26	
5	IO_L134P_YY	AK27	
5	IO_VREF_L134N_YY	AL29	
5	IO_L135P_YY	AN31	
5	IO_L135N_YY	AJ27	

Table 14: BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin#	See Note
NA	GND	A29	
NA	GND	A32	
NA	GND	A33	
NA	GND	B1	
NA	GND	B6	
NA	GND	B9	
NA	GND	B15	
NA	GND	B23	
NA	GND	B27	
NA	GND	B31	
NA	GND	C2	
NA	GND	E1	
NA	GND	F32	
NA	GND	G2	
NA	GND	G33	
NA	GND	J32	
NA	GND	K1	
NA	GND	L2	
NA	GND	M33	
NA	GND	P1	
NA	GND	P33	
NA	GND	R32	
NA	GND	T1	
NA	GND	V33	
NA	GND	W2	
NA	GND	Y1	
NA	GND	Y33	
NA	GND	AB1	
NA	GND	AC32	
NA	GND	AD33	
NA	GND	AE2	
NA	GND	AG1	
NA	GND	AG32	
NA	GND	AH2	
NA	GND	AJ33	

Table 14: BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin#	See Note
NA	GND	AL32	
NA	GND	AM3	
NA	GND	AM7	
NA	GND	AM11	
NA	GND	AM19	
NA	GND	AM25	
NA	GND	AM28	
NA	GND	AM33	
NA	GND	AN1	
NA	GND	AN2	
NA	GND	AN5	
NA	GND	AN10	
NA	GND	AN14	
NA	GND	AN16	
NA	GND	AN20	
NA	GND	AN22	
NA	GND	AN27	
NA	GND	AN33	

Notes:

1. V_{REF} or I/O option only in the XCV2000E; otherwise, I/O option only.
2. V_{REF} or I/O option only in the XCV1600E & 2000E; otherwise, I/O option only.
3. V_{REF} or I/O option only in the XCV1000E, 1600E, & 2000E; otherwise, I/O option only.
4. V_{REF} or I/O option only in the XCV600E, 1000E, 1600E, & 2000E; otherwise, I/O option only.

Table 16: FG256 Package — XCV50E, XCV100E, XCV200E, XCV300E

Bank	Pin Description	Pin #
4	IO_L43P_Y	P12
4	IO_VREF_L43N_Y	R13 ²
4	IO_L44P_YY	N12
4	IO_L44N_YY	T13
4	IO_VREF_L45P_YY	T12
4	IO_L45N_YY	P11
4	IO_L46P_Y	R12
4	IO_L46N_Y	N11
4	IO_VREF_L47P_YY	T11 ¹
4	IO_L47N_YY	M11
4	IO_L48P_YY	R11
4	IO_L48N_YY	T10
4	IO_L49P_Y	R10
4	IO_L49N_Y	M10
4	IO_VREF_L50P_Y	P9
4	IO_L50N_Y	T9
4	IO_L51P_Y	N10
4	IO_L51N_Y	R9
4	IO_LVDS_DLL_L52P	N9
5	GCK1	R8
5	IO	N7
5	IO	T7
5	IO_LVDS_DLL_L52N	T8
5	IO_L53P_Y	R7
5	IO_VREF_L53N_Y	P8
5	IO_L54P_Y	P7
5	IO_L54N_Y	T6
5	IO_L55P_YY	M7
5	IO_L55N_YY	R6
5	IO_L56P_YY	P6
5	IO_VREF_L56N_YY	R5 ¹
5	IO_L57P_Y	N6
5	IO_L57N_Y	T5
5	IO_L58P_YY	M6

Table 16: FG256 Package — XCV50E, XCV100E, XCV200E, XCV300E

Bank	Pin Description	Pin #
5	IO_VREF_L58N_YY	T4
5	IO_L59P_YY	T3
5	IO_L59N_YY	P5
5	IO_VREF_L60P_Y	T2 ²
5	IO_L60N_Y	N5
6	IO_L61N_YY	M3
6	IO_L61P_YY	R1
6	IO_L62N	M4
6	IO_VREF_L62P	N2 ²
6	IO_L63N_YY	L5
6	IO_L63P_YY	P1
6	IO_VREF_L64N_Y	N1
6	IO_L64P_Y	L3
6	IO_L65N	M2
6	IO_L65P	L4
6	IO_VREF_L66N_Y	M1 ¹
6	IO_L66P_Y	K4
6	IO_L67N_YY	L2
6	IO_L67P_YY	L1
6	IO_L68N	K3
6	IO_L68P	K1
6	IO_L69N_YY	K2
6	IO_L69P_YY	K5
6	IO_VREF_L70N_Y	J3
6	IO_L70P_Y	J1
6	IO_L71N	J4
6	IO_L71P	H1
6	IO	J2
7	IO	C2
7	IO_L72N_YY	G1
7	IO_L72P_YY	H4
7	IO_L73N	G5
7	IO_L73P	H2

Table 20: FG676 — XCV400E, XCV600E

Bank	Pin Description	Pin #
0	IO_L9N	A7
0	IO_L9P	D9
0	IO_L10N	B8
0	IO_VREF_L10P	G10
0	IO_L11N_YY	C9
0	IO_L11P_YY	F10
0	IO_L12N_Y	A8
0	IO_L12P_Y	E10
0	IO_L13N_YY	G11
0	IO_L13P_YY	D10
0	IO_L14N_YY	B10
0	IO_L14P_YY	F11
0	IO_L15N	C10
0	IO_L15P	E11
0	IO_L16N_YY	G12
0	IO_L16P_YY	D11
0	IO_VREF_L17N_YY	C11
0	IO_L17P_YY	F12
0	IO_L18N_YY	A11
0	IO_L18P_YY	E12
0	IO_L19N_Y	D12
0	IO_L19P_Y	C12
0	IO_VREF_L20N_Y	A12
0	IO_L20P_Y	H13
0	IO_LVDS_DLL_L21N	B13
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1	GCK2	C13
1	IO	A13 ¹
1	IO	A16 ¹
1	IO	A19
1	IO	A20
1	IO	A22
1	IO	A24 ¹
1	IO	B15 ¹
1	IO	B17 ¹
1	IO	B23
1	IO_LVDS_DLL_L21P	F14

Table 20: FG676 — XCV400E, XCV600E

Bank	Pin Description	Pin #
1	IO_L22N	E14
1	IO_L22P	F13
1	IO_L23N_Y	D14
1	IO_VREF_L23P_Y	A14
1	IO_L24N_Y	C14
1	IO_L24P_Y	H14
1	IO_L25N_YY	G14
1	IO_L25P_YY	C15
1	IO_L26N_YY	E15
1	IO_VREF_L26P_YY	D15
1	IO_L27N_YY	C16
1	IO_L27P_YY	F15
1	IO_L28N	G15
1	IO_L28P	D16
1	IO_L29N_YY	E16
1	IO_L29P_YY	A17
1	IO_L30N_YY	C17
1	IO_L30P_YY	E17
1	IO_L31N_Y	F16
1	IO_L31P_Y	D17
1	IO_L32N_YY	F17
1	IO_L32P_YY	C18
1	IO_L33N_YY	A18
1	IO_VREF_L33P_YY	G16
1	IO_L34N_YY	C19
1	IO_L34P_YY	G17
1	IO_L35N_Y	D18
1	IO_VREF_L35P_Y	B19 ²
1	IO_L36N_Y	D19
1	IO_L36P_Y	E18
1	IO_L37N_YY	F18
1	IO_L37P_YY	B20
1	IO_L38N_YY	G19
1	IO_VREF_L38P_YY	C20
1	IO_L39N_YY	G18
1	IO_L39P_YY	E19
1	IO_L40N_YY	A21

Table 22: FG680-XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin #
1	IO	C5
1	IO_LVDS_DLL_L29P	A19
1	IO_L30N_Y	C21
1	IO_VREF_L30P_Y	B19 ²
1	IO_L31N_Y	C19
1	IO_L31P_Y	A18
1	IO_L32N_YY	D19
1	IO_VREF_L32P_YY	B18
1	IO_L33N_YY	C18
1	IO_L33P_YY	A17
1	IO_L34N_Y	D18
1	IO_L34P_Y	B17
1	IO_L35N_Y	E18
1	IO_L35P_Y	A16
1	IO_L36N_YY	C17
1	IO_VREF_L36P_YY	D17
1	IO_L37N_YY	B16
1	IO_L37P_YY	E17
1	IO_L38N_Y	A15
1	IO_L38P_Y	C16
1	IO_L39N_Y	B15
1	IO_L39P_Y	D16
1	IO_L40N_YY	A14
1	IO_VREF_L40P_YY	B14 ¹
1	IO_L41N_YY	C15
1	IO_L41P_YY	A13
1	IO_L42N_Y	D15
1	IO_L42P_Y	B13
1	IO_L43N_Y	C14
1	IO_L43P_Y	A12
1	IO_L44N_YY	D14
1	IO_L44P_YY	C13
1	IO_L45N_YY	B12
1	IO_VREF_L45P_YY	D13
1	IO_L46N_Y	A11
1	IO_L46P_Y	C12

Table 22: FG680-XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin #
1	IO_L47N_Y	B11
1	IO_L47P_Y	C11
1	IO_L48N_YY	A10
1	IO_VREF_L48P_YY	D11
1	IO_L49N_YY	B10
1	IO_L49P_YY	C10
1	IO_L50N_Y	A9
1	IO_VREF_L50P_Y	D10 ³
1	IO_L51N_Y	B9
1	IO_L51P_Y	C9
1	IO_L52N_YY	A8
1	IO_VREF_L52P_YY	B8
1	IO_L53N_YY	D9
1	IO_L53P_YY	A7
1	IO_L54N_Y	C8
1	IO_L54P_Y	B7
1	IO_L55N_Y	D8
1	IO_L55P_Y	A6
1	IO_L56N_YY	C7
1	IO_VREF_L56P_YY	B6
1	IO_L57N_YY	D7
1	IO_L57P_YY	A5
1	IO_L58N_Y	C6
1	IO_VREF_L58P_Y	B5 ¹
1	IO_L59N_Y	D6
1	IO_L59P_Y	A4
1	IO_WRITE_L60N_YY	B4
1	IO_CS_L60P_YY	D5
2	IO	D1
2	IO	F4
2	IO_DOUT_BUSY_L61P_YY	E3
2	IO_DIN_D0_L61N_YY	C2
2	IO_L62P_Y	D3
2	IO_L62N_Y	F3
2	IO_VREF_L63P	D2 ¹

Table 22: FG680 - XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin #
NA	GND	D20
NA	GND	D12
NA	GND	C39
NA	GND	C37
NA	GND	C3
NA	GND	C20
NA	GND	C1
NA	GND	B39
NA	GND	B38
NA	GND	B2
NA	GND	B1
NA	GND	AW39
NA	GND	AW38
NA	GND	AW37
NA	GND	AW3
NA	GND	AW2
NA	GND	AW1
NA	GND	AV39
NA	GND	AV38
NA	GND	AV2
NA	GND	AV1
NA	GND	AU39
NA	GND	AU37
NA	GND	AU3
NA	GND	AU20
NA	GND	AU1
NA	GND	AT4
NA	GND	AT36
NA	GND	AT28
NA	GND	AT20
NA	GND	AT12
NA	GND	AR5
NA	GND	AR35
NA	GND	AR28
NA	GND	AR21
NA	GND	AR20

Table 22: FG680 - XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin #
NA	GND	AR19
NA	GND	AR12
NA	GND	AH5
NA	GND	AH4
NA	GND	AH36
NA	GND	AH35
NA	GND	AA5
NA	GND	AA35
NA	GND	A39
NA	GND	A38
NA	GND	A37
NA	GND	A3
NA	GND	A2
NA	GND	A1

Notes:

1. V_{REF} or I/O option only in the XCV1000E, 1600E, 2000E; otherwise, I/O option only.
2. V_{REF} or I/O option only in the XCV1600E, 2000E; otherwise, I/O option only.
3. V_{REF} or I/O option only in the XCV2000E; otherwise, I/O option only.

Table 24: FG860 — XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin #
4	IO_L147N_YY	AW7
4	IO_L148P_Y	AY7
4	IO_L148N_Y	BB8
4	IO_L149P_Y	BA9
4	IO_L149N_Y	AV8
4	IO_L150P_YY	AW8
4	IO_L150N_YY	BA10
4	IO_VREF_L151P_YY	BB10
4	IO_L151N_YY	AY8
4	IO_L152P_Y	AV9
4	IO_L152N_Y	BA11
4	IO_VREF_L153P_Y	BB11 ²
4	IO_L153N_Y	AW9
4	IO_L154P_YY	AY9
4	IO_L154N_YY	BA12
4	IO_VREF_L155P_YY	BB12
4	IO_L155N_YY	AV10
4	IO_L156P_Y	BA13
4	IO_L156N_Y	AW10
4	IO_L157P_Y	BB13
4	IO_L157N_Y	AY10
4	IO_VREF_L158P_YY	AV11
4	IO_L158N_YY	BA14
4	IO_L159P_YY	AW11
4	IO_L159N_YY	BB14
4	IO_L160P_Y	AV12
4	IO_L160N_Y	BA15
4	IO_L161P_Y	AW12
4	IO_L161N_Y	AY15
4	IO_L162P_Y	AW13
4	IO_L162N_Y	BB15
4	IO_L163P_Y	AV14
4	IO_L163N_Y	BA16
4	IO_L164P_YY	AW14
4	IO_L164N_YY	AY16
4	IO_VREF_L165P_YY	BB16
4	IO_L165N_YY	AV15

Table 24: FG860 — XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin #
4	IO_L166P_Y	AY17
4	IO_L166N_Y	AW15
4	IO_L167P_Y	BB17
4	IO_L167N_Y	AU16
4	IO_L168P_YY	AV16
4	IO_L168N_YY	AY18
4	IO_VREF_L169P_YY	AW16
4	IO_L169N_YY	BA18
4	IO_L170P_Y	BB19
4	IO_L170N_Y	AW17
4	IO_L171P_Y	AY19
4	IO_L171N_Y	AV18
4	IO_L172P_YY	AW18
4	IO_L172N_YY	BB20
4	IO_VREF_L173P_YY	AY20
4	IO_L173N_YY	AV19
4	IO_L174P_Y	BB21
4	IO_L174N_Y	AW19
4	IO_VREF_L175P_Y	AY21 ¹
4	IO_L175N_Y	AV20
4	IO_LVDS_DLL_L176P	AW20
5	GCK1	AY22
5	IO	AV24
5	IO	AV34
5	IO	AW27
5	IO	AW36
5	IO	AY23
5	IO	AY31
5	IO	AY33
5	IO	BA26
5	IO	BA29
5	IO	BA33
5	IO	BB25
5	IO_LVDS_DLL_L176N	AW21
5	IO_L177P_Y	BB22
5	IO_VREF_L177N_Y	AW22 ¹

**Table 25: FG860 Differential Pin Pair Summary
XCV1000E, XCV1600E, XCV2000E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
256	7	T38	T41	✓	-
257	7	T42	R39	1	VREF
258	7	R38	R42	2	-
259	7	P39	R40	4	-
260	7	P38	R41	2	-
261	7	N39	P42	1	-
262	7	M39	P40	3	-
263	7	M38	P41	✓	-
264	7	L39	N42	✓	VREF
265	7	N41	L38	2	-
266	7	M42	K40	✓	-
267	7	K38	M40	✓	VREF
268	7	J40	M41	2	-
269	7	L40	J39	5	VREF
270	7	L41	J38	✓	-
271	7	H39	K42	✓	VREF
272	7	H38	K41	1	-
273	7	G40	J41	2	-
274	7	G39	H42	✓	-
275	7	G42	G38	1	VREF
276	7	F40	G41	2	-
277	7	F41	F42	4	-
278	7	E42	F39	2	VREF
279	7	E41	E40	1	-
280	7	D41	E39	3	-

Notes:

1. AO in the XCV1000E, 2000E.
2. AO in the XCV1000E, 1600E.
3. AO in the XCV2000E.
4. AO in the XCV1600E.
5. AO in the XCV1000E.

FG900 Fine-Pitch Ball Grid Array Package

XCV600E, XCV1000E, and XCV1600E devices in the FG900 fine-pitch Ball Grid Array package have footprint compatibility. Pins labeled IO_VREF can be used as either in all parts unless device-dependent as indicated in the footnotes. If the pin is not used as V_{REF}, it can be used as general I/O. Immediately following Table 26, see Table 27 for Differential Pair information.

Table 26: FG900 — XCV600E, XCV1000E, XCV1600E

Bank	Pin Description	Pin #
0	GCK3	C15
0	IO	A7 ⁴
0	IO	A13 ⁴
0	IO	C5 ⁴
0	IO	C6 ⁴
0	IO	C14 ⁴
0	IO	D8 ⁵
0	IO	D10
0	IO	D13 ⁴
0	IO	E6
0	IO	E9 ⁵
0	IO	E14 ⁵
0	IO	F9 ⁴
0	IO	F14 ⁵
0	IO	G15
0	IO	K11 ⁵
0	IO	K12
0	IO	L13 ⁴
0	IO_L0N_YY	C4 ⁴
0	IO_L0P_YY	F7 ³
0	IO_L1N_Y	D5
0	IO_L1P_Y	G8
0	IO_VREF_L2N_Y	A3 ¹
0	IO_L2P_Y	H9
0	IO_L3N_Y	B4 ⁴
0	IO_L3P_Y	J10 ⁴
0	IO_L4N_YY	A4
0	IO_L4P_YY	D6
0	IO_VREF_L5N_YY	E7
0	IO_L5P_YY	B5

Table 26: FG900 — XCV600E, XCV1000E, XCV1600E

Bank	Pin Description	Pin #
NA	VCCO_0	C12
NA	VCCO_1	B25
NA	VCCO_1	C19
NA	VCCO_1	M18
NA	VCCO_1	M17
NA	VCCO_1	L17
NA	VCCO_1	H17
NA	VCCO_1	L16
NA	VCCO_1	M16
NA	VCCO_2	F29
NA	VCCO_2	M28
NA	VCCO_2	P23
NA	VCCO_2	R20
NA	VCCO_2	P20
NA	VCCO_2	R19
NA	VCCO_2	N19
NA	VCCO_2	P19
NA	VCCO_3	AE29
NA	VCCO_3	W28
NA	VCCO_3	U23
NA	VCCO_3	U20
NA	VCCO_3	T20
NA	VCCO_3	V19
NA	VCCO_3	T19
NA	VCCO_3	U19
NA	VCCO_4	AJ25
NA	VCCO_4	AH19
NA	VCCO_4	W18
NA	VCCO_4	AC17
NA	VCCO_4	Y17
NA	VCCO_4	W17
NA	VCCO_4	W16
NA	VCCO_4	Y16
NA	VCCO_5	AJ6
NA	VCCO_5	Y15
NA	VCCO_5	W15
NA	VCCO_5	AC14

Table 26: FG900 — XCV600E, XCV1000E, XCV1600E

Bank	Pin Description	Pin #
NA	VCCO_5	Y14
NA	VCCO_5	W14
NA	VCCO_5	W13
NA	VCCO_5	AH12
NA	VCCO_6	AE2
NA	VCCO_6	V12
NA	VCCO_6	U12
NA	VCCO_6	T12
NA	VCCO_6	U11
NA	VCCO_6	T11
NA	VCCO_6	U8
NA	VCCO_6	W3
NA	VCCO_7	F2
NA	VCCO_7	R12
NA	VCCO_7	P12
NA	VCCO_7	N12
NA	VCCO_7	R11
NA	VCCO_7	P11
NA	VCCO_7	P8
NA	VCCO_7	M3
NA	GND	Y18
NA	GND	AH7
NA	GND	AK30
NA	GND	AJ30
NA	GND	B30
NA	GND	A30
NA	GND	AK29
NA	GND	AJ29
NA	GND	AC29
NA	GND	H29
NA	GND	B29
NA	GND	A29
NA	GND	AH28
NA	GND	V28
NA	GND	N28
NA	GND	C28

Revision History

The following table shows the revision history for this document.

Date	Version	Revision
12/7/99	1.0	Initial Xilinx release.
1/10/00	1.1	Re-released with spd.txt v. 1.18, FG860/900/1156 package information, and additional DLL, Select RAM and SelectI/O information.
1/28/00	1.2	Added Delay Measurement Methodology table, updated SelectI/O section, Figures 30, 54, & 55, text explaining Table 5, T_{BYP} values, buffered Hex Line info, p. 8, I/O Timing Measurement notes, notes for Tables 15, 16, and corrected F1156 pinout table footnote references.
2/29/00	1.3	Updated pinout tables, V_{CC} page 20, and corrected Figure 20.
5/23/00	1.4	Correction to table on p. 22.
7/10/00	1.5	<ul style="list-style-type: none"> • Numerous minor edits. • Data sheet upgraded to Preliminary. • Preview -8 numbers added to Virtex-E Electrical Characteristics tables.
8/1/00	1.6	<ul style="list-style-type: none"> • Reformatted entire document to follow new style guidelines. • Changed speed grade values in tables on pages 35-37.
9/20/00	1.7	<ul style="list-style-type: none"> • Min values added to Virtex-E Electrical Characteristics tables. • XCV2600E and XCV3200E numbers added to Virtex-E Electrical Characteristics tables (Module 3). • Corrected user I/O count for XCV100E device in Table 1 (Module 1). • Changed several pins to "No Connect in the XCV100E" and removed duplicate V_{CCINT} pins in Table ~ (Module 4). • Changed pin J10 to "No connect in XCV600E" in Table 74 (Module 4). • Changed pin J30 to "V_{REF} or I/O option only in the XCV600E" in Table 74 (Module 4). • Corrected pair 18 in Table 75 (Module 4) to be "AO in the XCV1000E, XCV1600E".
11/20/00	1.8	<ul style="list-style-type: none"> • Upgraded speed grade -8 numbers in Virtex-E Electrical Characteristics tables to Preliminary. • Updated minimums in Table 13 and added notes to Table 14. • Added note 2 to Absolute Maximum Ratings. • Changed speed grade -8 numbers for $T_{SHCKO32}$, T_{REG}, T_{BCCS}, and T_{ICKOF}. • Changed all minimum hold times to -0.4 under Global Clock Set-Up and Hold for LVTTL Standard, with DLL. • Revised maximum T_{DLLPW} in -6 speed grade for DLL Timing Parameters. • Changed GCLK0 to BA22 for FG860 package in Table 46.
2/12/01	1.9	<ul style="list-style-type: none"> • Revised footnote for Table 14. • Added numbers to Virtex-E Electrical Characteristics tables for XCV1000E and XCV2000E devices. • Updated Table 27 and Table 78 to include values for XCV400E and XCV600E devices. • Revised Table 62 to include pinout information for the XCV400E and XCV600E devices in the BG560 package. • Updated footnotes 1 and 2 for Table 76 to include XCV2600E and XCV3200E devices.